

# Vishay High Power Products

# Ultrafast Soft Recovery Diode, 150 A FRED Pt<sup>TM</sup>



PRODUCT SUMMARY			
t <sub>rr</sub>	60 ns		
I <sub>F(AV)</sub>	150 A		
V <sub>R</sub>	400 V		

#### **FEATURES**

- · Ultrafast recovery
- 175 °C operating junction temperature
- Screw mounting only
- · Lead (Pb)-free plating
- Designed and qualified for industrial level
- Compliant to RoHS directive 2002/95/EC

### **BENEFITS**

- · Reduced RFI and EMI
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

### **DESCRIPTION/APPLICATIONS**

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	$V_{R}$		400	V
Continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 104 °C	150	
Single pulse forward current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	1500	Α
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20 kHz	300	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 200 μΑ		-	-	
		I <sub>F</sub> = 150 A	-	1.07	1.3	V
Forward voltage	$V_{F}$	I <sub>F</sub> = 150 A, T <sub>J</sub> = 175 °C	-	0.9	1.1	
		I <sub>F</sub> = 150 A, T <sub>J</sub> = 125 °C	=	0.96	1.17	
Deverage leader to assume the	I <sub>R</sub>	$V_R = V_R$ rated	-	-	50	μΑ
Reverse leakage current		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	4	mA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 400 V		100	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 3.5 -		nΗ		

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# 150EBU04



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	-	60	
Reverse recovery time t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	93	-	ns	
	T <sub>J</sub> = 125 °C		-	172	=		
Peak recovery current I <sub>RRM</sub>	_	T <sub>J</sub> = 25 °C	$I_F = 150 \text{ A}$ $V_R = 200 \text{ V}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$	-	11	-	Α
	IRRM	T <sub>J</sub> = 125 °C		-	20	-	
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	490	=	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1740	=	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.35	K/W
Thermal resistance, junction to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.2	-	- r./vv
Weight			-	-	5.02	g
vveigni			-	0.18	-	OZ.
Mounting torque			1.2 (10)	-	2.4 (20)	N ⋅ m (lbf ⋅ in)
Marking device		Case style PowerTab <sup>TM</sup>		150E	BU04	•

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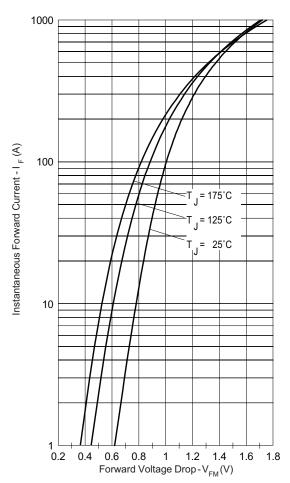


Fig. 1 - Maximum Forward Voltage Drop Characteristics

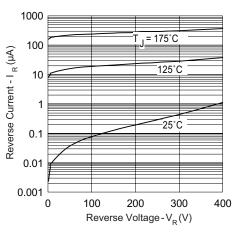


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

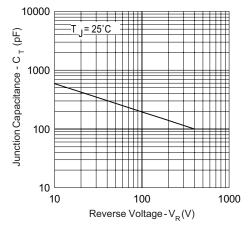


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

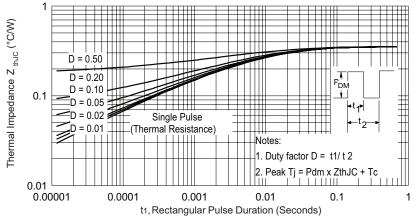


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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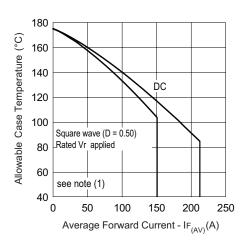


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

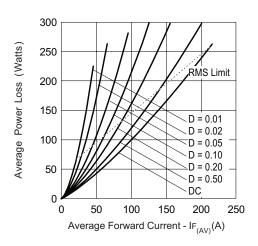


Fig. 6 - Forward Power Loss Characteristics

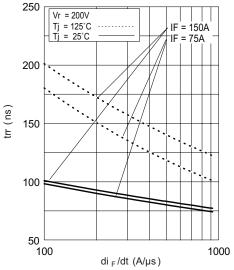


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

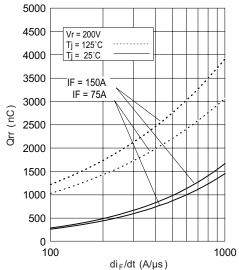


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \ x \ V_{FM} \ \text{at} \ (I_{F(AV)}/D) \ (\text{see fig. 6}); \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \ x \ I_{R} \ (1 - D); \ I_{R} \ \text{at} \ V_{R1} = \text{Rated} \ V_{R} \\ \end{array}$ 

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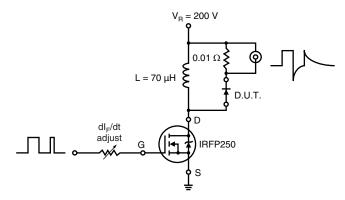
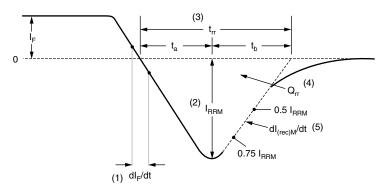


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{\text{RRM}}$  peak reverse recovery current
- (3)  $t_{\rm rr}$  reverse recovery time measured from zero crossing point of negative going  $I_{\rm F}$  to point where a line passing through 0.75  $I_{\rm RRM}$  and 0.50  $I_{\rm RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

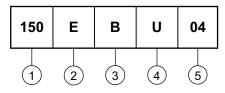
Fig. 10 - Reverse Recovery Waveform and Definitions



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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Current rating (150 = 150 A)

2 - Single diode

3 - PowerTab<sup>TM</sup> (ultrafast/hyperfast only)

4 - Ultrafast recovery

- Voltage rating (04 = 400 V)

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95240</u>				
Part marking information	www.vishay.com/doc?95370			
Application note	www.vishay.com/doc?95179			

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